

# **Datasheet**

## **250V Three-phase Gate Driver**

### **FD6288**

Fortior Technology (Shenzhen) Co., Ltd.

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## **FD6288 250V Three-phase Gate Driver**

### **1 System Introduction**

#### **1.1 Overview**

FD6288 is an integrated circuit (IC) that integrates three independent half-bridge gate drivers. It is specially designed for high-voltage and high-speed drive MOSFETs and operates up to +250V.

FD6288 supports under-voltage lockout (UVLO) feature, protecting the power device from operating with insufficient voltage.

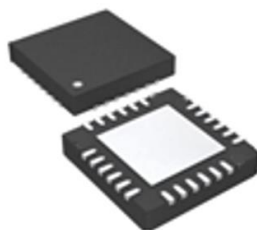
FD6288 also provides cross-conduction prevention and deadtime insertion to effectively protect the power IC and prevent both MOSFETs of each half-bridge from switching on at the same time.

FD6288 has built-in input signal filtering module to avoid input noise interference.

#### **1.2 Packages**



TSSOP-20



QFN-24

#### **1.3 Features**

- Fully operational to +250V
- Power supply: 5V to 20V
- Three independent half-bridge drivers
- Output current: +1.5A/-1.8A
- 3.3V and 5V logic input compatible
- $V_{CC}/V_{BS}$  UVLO
- Cross-conduction prevention logic
- 200ns deadtime
- Built-in input filtering module
- Matched propagation delay for high-side and low-side channels
- Outputs in phase with inputs

#### **1.4 Applications**

Motor drivers

## 1.5 Typical Application Diagram

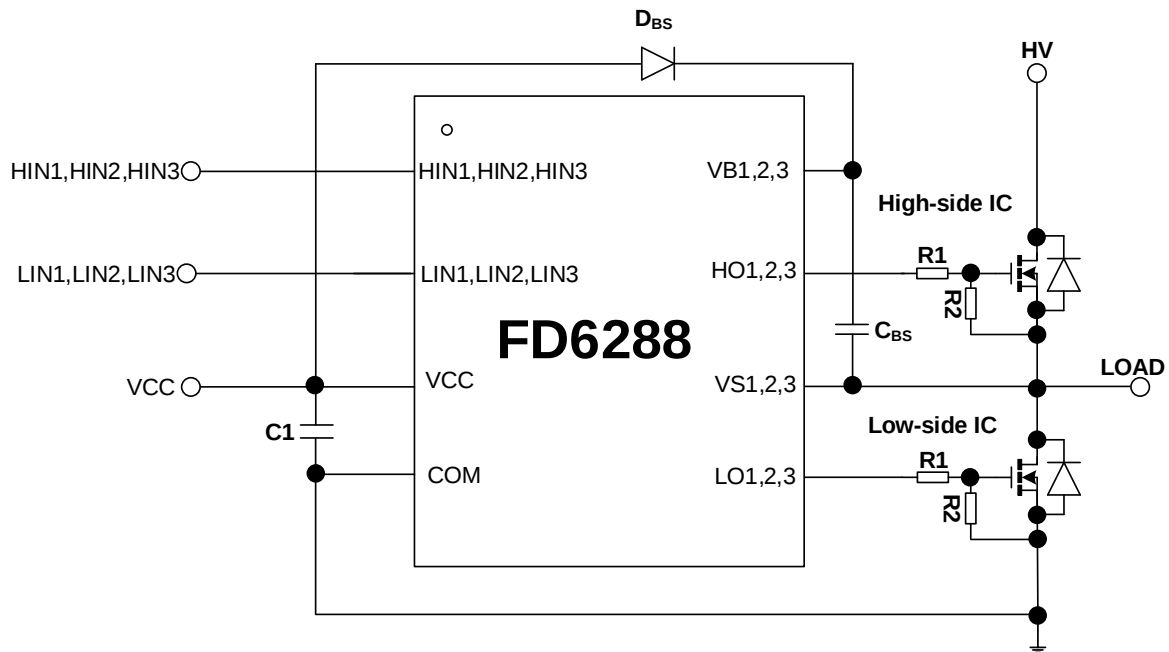


Figure 1-1 Typical Application Diagram of FD6288

C1: Power filter capacitor with 10 $\mu$ F optional. It shall be as close to the chip pin as possible.

R1: Gate drive resistor. The resistance depends on deadtime and the device being driven.

R2: MOS gate and source resistor.

D<sub>BS</sub>: Bootstrap diode. Schottky diode with high reverse breakdown voltage and short recovery time is preferred.

C<sub>BS</sub>: Bootstrap capacitor. Ceramic capacitor or tantalum capacitor is preferred. It shall be as close as possible to the chip pin.

Note: The above circuits and parameters are for reference only. The actual circuit shall be designed with the measured results.

## 1.6 Functional Block Diagram

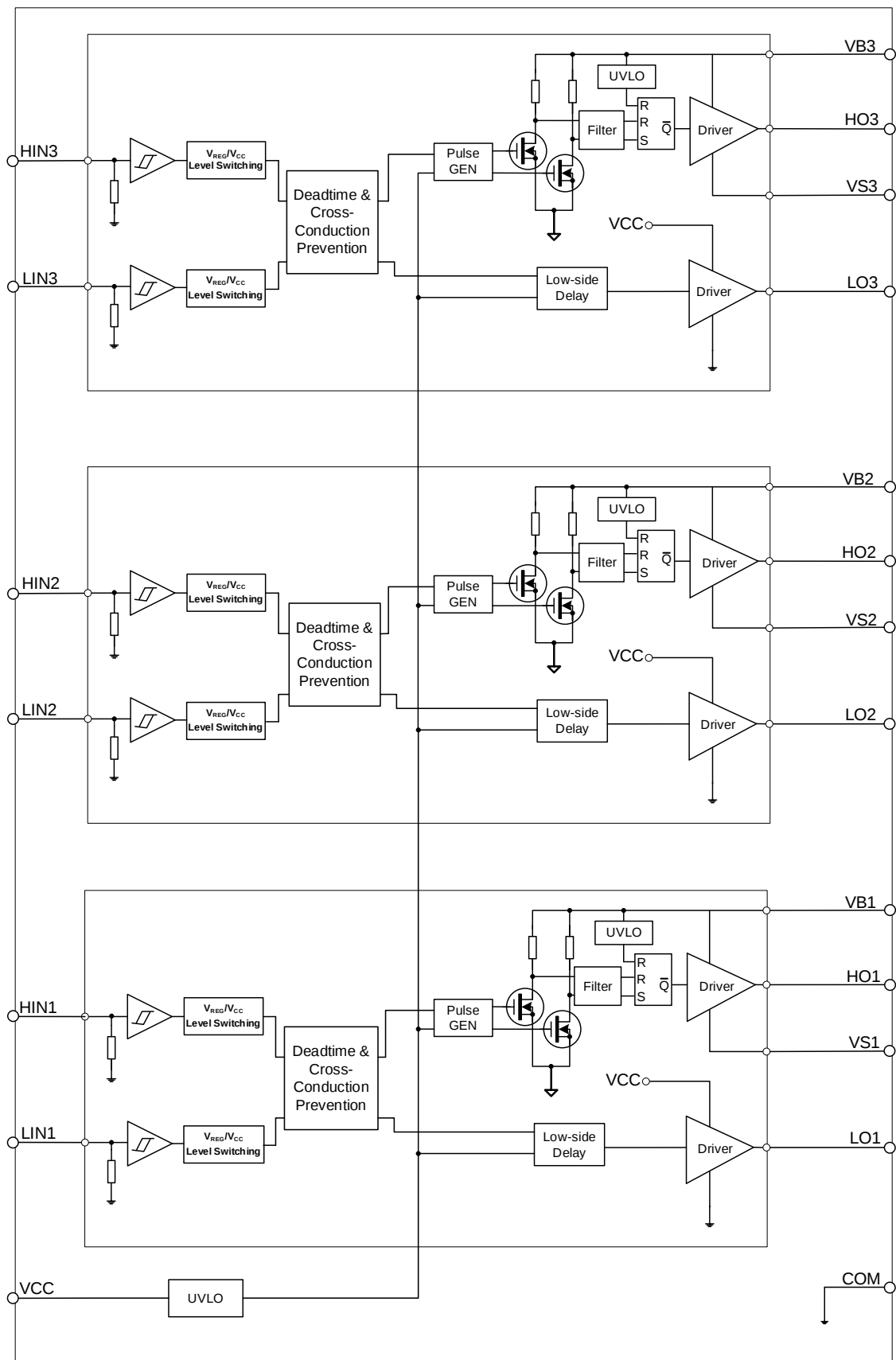


Figure 1-2 Functional Block Diagram of FD6288

## 1.7 Pin Definitions

### 1.7.1 FD6288T TSSOP20 Pin Diagram

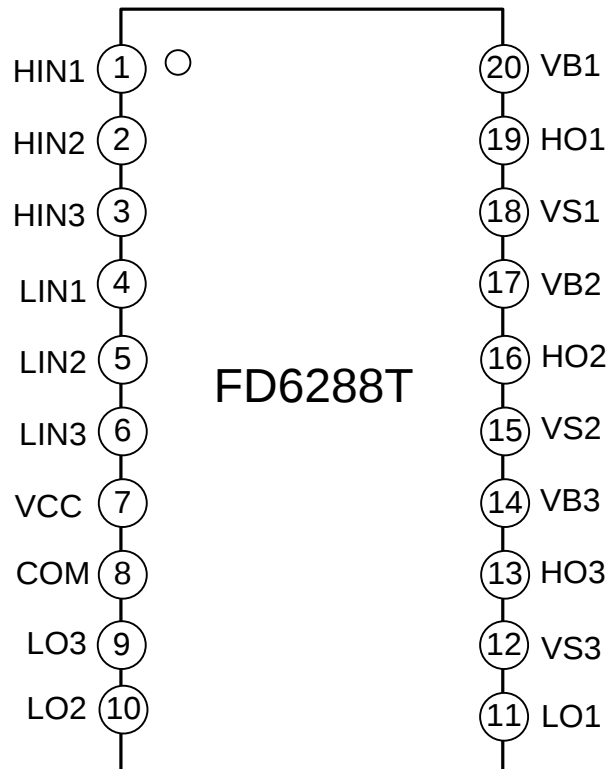


Figure 1-3 Pin Diagram of FD6288T TSSOP20

### 1.7.2 FD6288T TSSOP20 Pin Descriptions

Table 1-1 FD6288T TSSOP20 Pin Descriptions

| Pin        | Name             | Description                         |
|------------|------------------|-------------------------------------|
| 1, 2, 3    | HIN1, HIN2, HIN3 | High-side Input                     |
| 4, 5, 6    | LIN1, LIN2, LIN3 | Low-side Input                      |
| 7          | VCC              | Low-side Power Supply               |
| 8          | COM              | Ground                              |
| 9, 10, 11  | LO3, LO2, LO1    | Low-side Output                     |
| 12, 15, 18 | VS3, VS2, VS1    | High-side Floating Offset Voltage   |
| 13, 16, 19 | HO3, HO2, HO1    | High-side Output                    |
| 14, 17, 20 | VB3, VB2, VB1    | High-side Floating Absolute Voltage |

### 1.7.3 FD6288Q QFN24 Pin Diagram

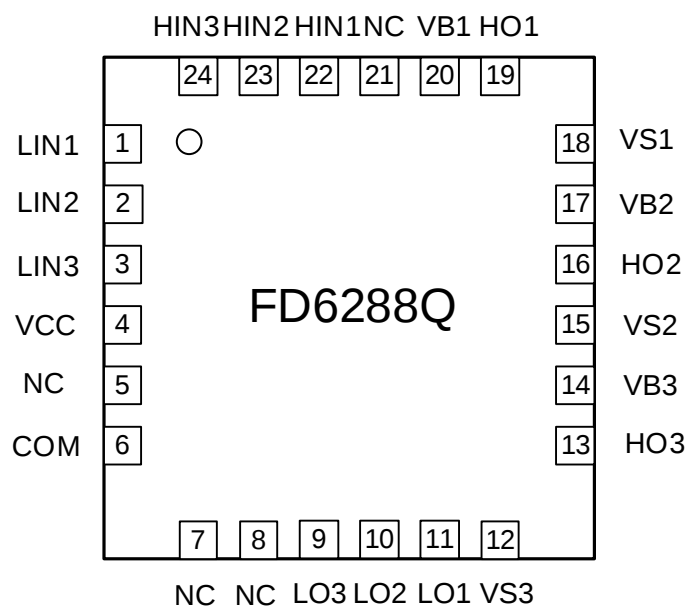


Figure 1-4 Pin Diagram of FD6288Q QFN24

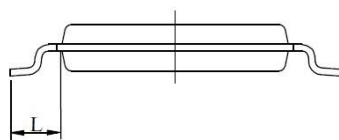
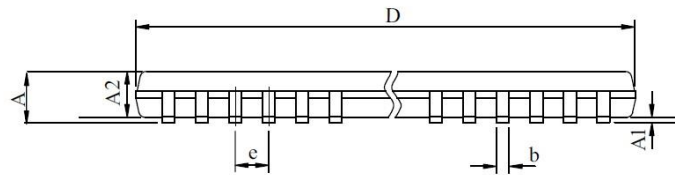
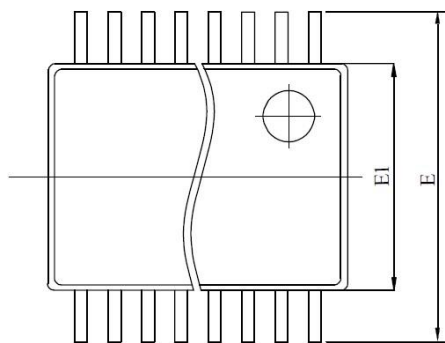
### 1.7.4 FD6288Q QFN24 Pin Descriptions

Table 1-2 FD6288Q QFN24 Pin Descriptions

| Pin         | Name             | Description                         |
|-------------|------------------|-------------------------------------|
| 22, 23, 24  | HIN1, HIN2, HIN3 | High-side Input                     |
| 1, 2, 3     | LIN1, LIN2, LIN3 | Low-side Input                      |
| 4           | VCC              | Low-side Power Supply               |
| 6           | COM              | Ground                              |
| 9, 10, 11   | LO3, LO2, LO1    | Low-side Output                     |
| 12, 15, 18  | VS3, VS2, VS1    | High-side Floating Offset Voltage   |
| 13, 16, 19  | HO3, HO2, HO1    | High-side Output                    |
| 14, 17, 20  | VB3, VB2, VB1    | High-side Floating Absolute Voltage |
| 5, 7, 8, 21 | NC               | Not Connected                       |

## 2 Package Information

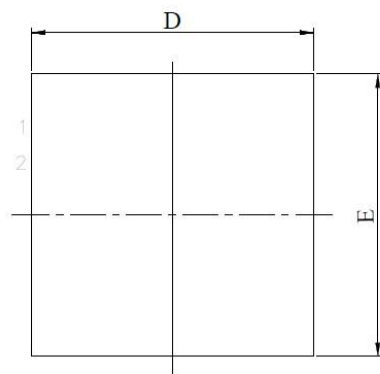
### 2.1 FD6288T TSSOP20



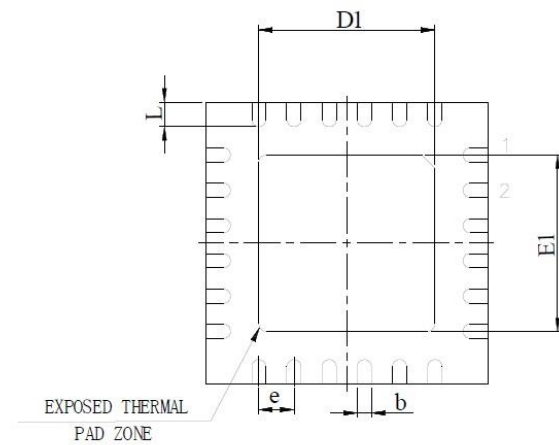
| TSSOP20 |            |      |      |
|---------|------------|------|------|
| SYMBOL  | MILLIMETER |      |      |
|         | MIN        | NOM  | MAX  |
| A       |            |      | 1.2  |
| A1      | 0.05       |      | 0.15 |
| A2      | 0.8        | 1    | 1.05 |
| E       | 6.2        | 6.4  | 6.6  |
| E1      | 4.3        | 4.4  | 4.5  |
| D       | 6.4        | 6.5  | 6.6  |
| L       | 0.45       | 0.6  | 0.75 |
| e       |            | 0.65 |      |
| b       | 0.2        |      | 0.28 |

| Product Number | Package Type | Marking ID | Package Method | Quantity |
|----------------|--------------|------------|----------------|----------|
| FD6288T        | TSSOP20      | FD6288T    | Tape & Reel    | 3000     |

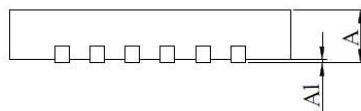
## 2.2 FD6288Q QFN24



TOP VIEW



BOTTOM VIEW



SIDE VIEW

| QFN24L |            |      |      |
|--------|------------|------|------|
| SYMBOL | MILLIMETER |      |      |
|        | MIN        | NOM  | MAX  |
| A      | 0.7        | 0.75 | 0.8  |
| A1     | 0          |      | 0.05 |
| E      | 3.9        | 4    | 4.1  |
| D      | 3.9        | 4    | 4.1  |
| E1     | 2.55       |      | 2.8  |
| D1     | 2.55       |      | 2.8  |
| L      | 0.3        | 0.4  | 0.5  |
| e      |            | 0.5  |      |
| b      | 0.2        |      | 0.3  |

| Product Number | Package Type | Marking ID | Package Method | Quantity |
|----------------|--------------|------------|----------------|----------|
| FD6288Q        | QFN24        | FD6288Q    | Tape & Reel    | 3000     |

### 3 Electrical Characteristics

#### 3.1 Absolute Maximum Ratings

Table 3-1 Absolute Maximum Ratings

(All pins are referenced to COM unless otherwise specified)

| Parameter                                       |         | Symbol        | Min. ~ Max.                          | Unit              |
|-------------------------------------------------|---------|---------------|--------------------------------------|-------------------|
| High-side Floating Absolute Voltage             |         | $V_{B1,2,3}$  | -0.3~275                             | V                 |
| High-side Floating Offset Voltage               |         | $V_{S1,2,3}$  | $V_{B1,2,3}-25 \sim V_{B1,2,3}+0.3$  | V                 |
| High-side Output Voltage                        |         | $V_{HO1,2,3}$ | $V_{S1,2,3}-0.3 \sim V_{B1,2,3}+0.3$ | V                 |
| Low-side Power Supply                           |         | $V_{CC}$      | -0.3~25                              | V                 |
| Low-side Output Voltage                         |         | $V_{LO1,2,3}$ | -0.3~ $V_{CC}+0.3$                   | V                 |
| Logic Input Voltage (HIN, LIN)                  |         | $V_{IN}$      | -0.3~ $V_{CC}+0.3$                   | V                 |
| Swing Rate of Offset Voltage                    |         | $dV_S/dt$     | $\leq 50$                            | V/ns              |
| Power Dissipation @ $T_A \leq 25^\circ\text{C}$ | TSSOP20 | $P_D$         | $\leq 1.25$                          | W                 |
|                                                 | QFN24   |               | $\leq 3.0$                           |                   |
| Junction-to-ambient Thermal Resistance          | TSSOP20 | $R_{thJA}$    | $\leq 100$                           | $^\circ\text{C}/$ |
|                                                 | QFN24   |               | $\leq 42$                            | W                 |
| Junction Temperature                            |         | $T_j$         | $\leq 150$                           | $^\circ\text{C}$  |
| Storage Temperature                             |         | $T_{stg}$     | -55~150                              | $^\circ\text{C}$  |

Notes:

- In any case, power dissipation shall not exceed  $P_D$ .
- The chip may get damaged if it operates under voltages above the absolute maximum ratings.

#### 3.2 Recommended Operating Conditions

Table 3-2 Recommended Operating Conditions<sup>[1]</sup>

(All voltages are referenced to COM unless otherwise specified)

| Parameter                                        | Symbol        | Min.                 | Max.              | Unit             |
|--------------------------------------------------|---------------|----------------------|-------------------|------------------|
| High-side Floating Absolute Voltage              | $V_{B1,2,3}$  | $V_{S1,2,3} + 5.0$   | $V_{S1,2,3} + 20$ | V                |
| High-side Floating Offset Voltage <sup>[2]</sup> | $V_{S1,2,3}$  | COM-4 <sup>[3]</sup> | 250               | V                |
| High-side Output Voltage                         | $V_{HO1,2,3}$ | $V_{S1,2,3}$         | $V_{B1,2,3}$      | V                |
| Low-side Power Supply                            | $V_{CC}$      | 5.0                  | 20                | V                |
| Low-side Output Voltage                          | $V_{LO1,2,3}$ | 0                    | $V_{CC}$          | V                |
| Logic Input Voltage (HIN, LIN)                   | $V_{IN}$      | 0                    | $V_{CC}$          | V                |
| Ambient Temperature                              | $T_A$         | -40                  | 125               | $^\circ\text{C}$ |

Notes:

[1] The reliability may get affected if the chip operates in an environment that exceeds the recommended conditions for a long period of time.

[2] The high-side floating offset voltage  $V_S$  is tested with 15V bias voltage.

[3] HO works normally when  $V_{S1,2,3}$  ranges from (COM-4V) to 250V.

### 3.3 Static Electrical Characteristics

Table 3-3 Static Electrical Characteristics

( $T_A = 25^\circ\text{C}$ ,  $V_{CC} = V_{BS1,2,3} = 15\text{V}$  and  $V_S = \text{COM}$  unless otherwise specified)

| Parameter                                     | Symbol      | Test Conditions                                                                | Min. | Typ. | Max. | Unit             |
|-----------------------------------------------|-------------|--------------------------------------------------------------------------------|------|------|------|------------------|
| High-level Input Threshold Voltage            | $V_{IH}$    |                                                                                | 2.7  | -    | -    | V                |
| Low-level Input Threshold Voltage             | $V_{IL}$    |                                                                                | -    | -    | 0.8  | V                |
| $V_{CC}$ UVLO Threshold Voltage               | $V_{CCUV+}$ |                                                                                | 4.2  | 4.6  | 5.0  | V                |
| $V_{CC}$ UVLO Reset Voltage                   | $V_{CCUV-}$ |                                                                                | 3.9  | 4.3  | 4.7  | V                |
| $V_{CC}$ UVLO Hysteresis Voltage              | $V_{CCUVH}$ |                                                                                | 0.2  | 0.3  | -    | V                |
| $V_{BS}$ UVLO Threshold Voltage               | $V_{BSUV+}$ |                                                                                | 4.2  | 4.6  | 5.0  | V                |
| $V_{BS}$ UVLO Reset Voltage                   | $V_{BSUV-}$ |                                                                                | 3.9  | 4.3  | 4.7  | V                |
| $V_{BS}$ UVLO Hysteresis Voltage              | $V_{BSUVH}$ |                                                                                | 0.2  | 0.3  | -    | V                |
| Leakage Current of Floating Power Supply      | $I_{LK}$    | $V_{B1,2,3} = V_{S1,2,3} = 250\text{V}$                                        | -    | 0.1  | 5.0  | $\mu\text{A}$    |
| $V_{BS}$ Quiescent Current                    | $I_{QBS}$   | $V_{IN} = 0\text{V}$ or $5\text{V}$                                            | -    | 180  | 270  | $\mu\text{A}$    |
| $V_{BS}$ Polyphase Current                    | $I_{PBS}$   | $f_{HIN1,2,3} = 20\text{kHz}$                                                  | -    | 180  | 270  | $\mu\text{A}$    |
| $V_{CC}$ Quiescent Current                    | $I_{QCC}$   | $V_{IN} = 0\text{V}$ or $5\text{V}$                                            | -    | 330  | 500  | $\mu\text{A}$    |
| $V_{CC}$ Polyphase Current                    | $I_{PCC}$   | $f_{LIN1,2,3} = 20\text{kHz}$                                                  | -    | 330  | 500  | $\mu\text{A}$    |
| LIN High-level Input Bias Current             | $I_{LIN+}$  | $V_{LIN} = 5\text{V}$                                                          | -    | 25   | 40   | $\mu\text{A}$    |
| LIN Low-level Input Bias Current              | $I_{LIN-}$  | $V_{LIN} = 0\text{V}$                                                          | -    | -    | 1    | $\mu\text{A}$    |
| HIN High-level Input Bias Current             | $I_{HIN+}$  | $V_{HIN} = 5\text{V}$                                                          | -    | 25   | 40   | $\mu\text{A}$    |
| HIN Low-level Input Bias Current              | $I_{HIN-}$  | $V_{HIN} = 0\text{V}$                                                          | -    | -    | 1    | $\mu\text{A}$    |
| Input Pull-down Resistance                    | $R_{IN}$    |                                                                                | 140  | 200  | 260  | $\text{K}\Omega$ |
| High-level Output Voltage                     | $V_{OH}$    | $I_O = 100\text{mA}$                                                           | -    | 0.6  | 0.9  | V                |
| Low-level Output Voltage                      | $V_{OL}$    | $I_O = 100\text{mA}$                                                           | -    | 0.3  | 0.45 | V                |
| High-level Output Short-circuit Pulse Current | $I_{OH}$    | $V_O = 0\text{V}$ , $V_{IN} = 5\text{V}$ ,<br>$\text{PWD} \leq 10\mu\text{s}$  | 1.1  | 1.5  | 1.9  | A                |
| Low-level Output Short-circuit Pulse Current  | $I_{OL}$    | $V_O = 15\text{V}$ , $V_{IN} = 0\text{V}$ ,<br>$\text{PWD} \leq 10\mu\text{s}$ | 1.3  | 1.8  | 2.3  | A                |
| $V_S$ Negative Offset Voltage                 | $V_{SN}$    |                                                                                | -    | -6.0 | -    | V                |

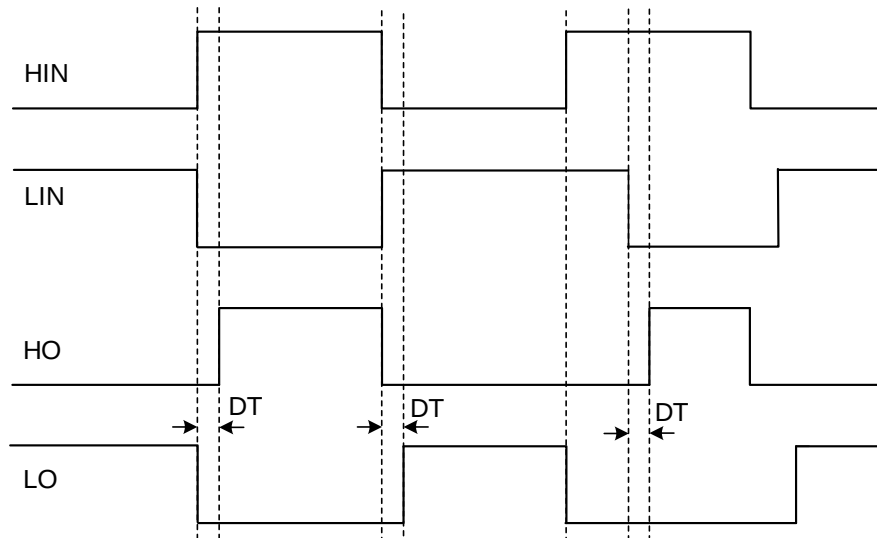
### 3.4 Dynamic Electrical Characteristics

Table 3-4 Dynamic Electrical Characteristics

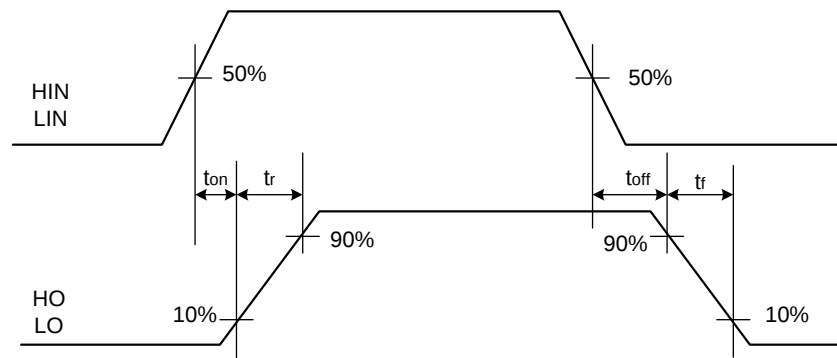
( $T_A=25^{\circ}\text{C}$ ,  $V_{CC}=V_{BS1,2,3}=15\text{V}$  and  $V_S=\text{COM}$  unless otherwise specified.)

| Parameter                  | Symbol    | Test Conditions     | Min. | Typ. | Max. | Unit |
|----------------------------|-----------|---------------------|------|------|------|------|
| Turn-on Propagation Delay  | $t_{on}$  |                     | -    | 300  | 450  | ns   |
| Turn-off Propagation Delay | $t_{off}$ |                     | -    | 100  | 160  | ns   |
| Turn-on Rise Time          | $t_r$     | $C_L=1000\text{pF}$ | -    | 12   | 25   | ns   |
| Turn-off Fall Time         | $t_f$     | $C_L=1000\text{pF}$ | -    | 12   | 25   | ns   |
| High-low Side Delay Match  | MT        |                     | -    | -    | 30   | ns   |
| Deadtime                   | DT        |                     | 100  | 200  | 300  | ns   |

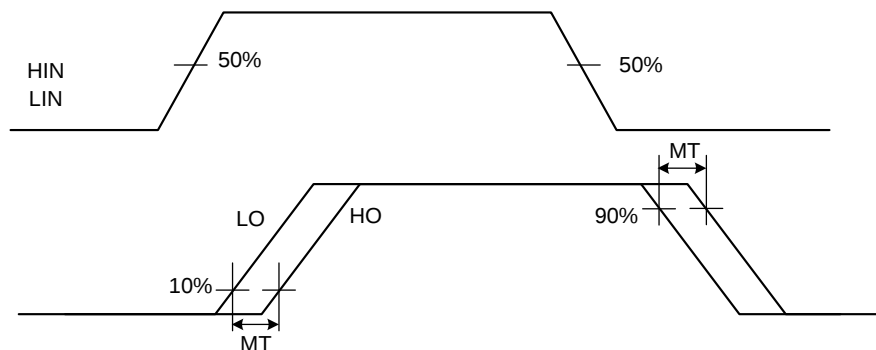
#### 4 Logic Function Timing Diagram



#### 5 Propagation Delay Test Standards

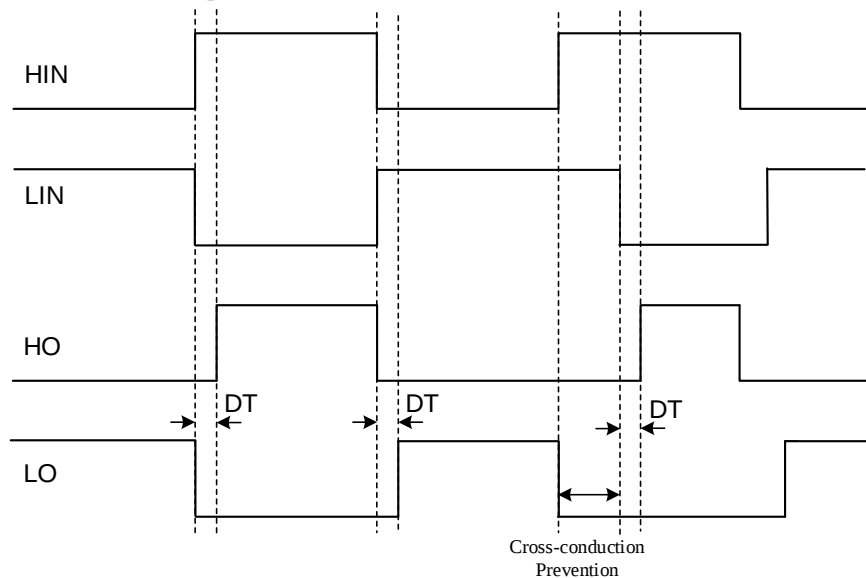


#### 6 Propagation Delay Matching Test Standards



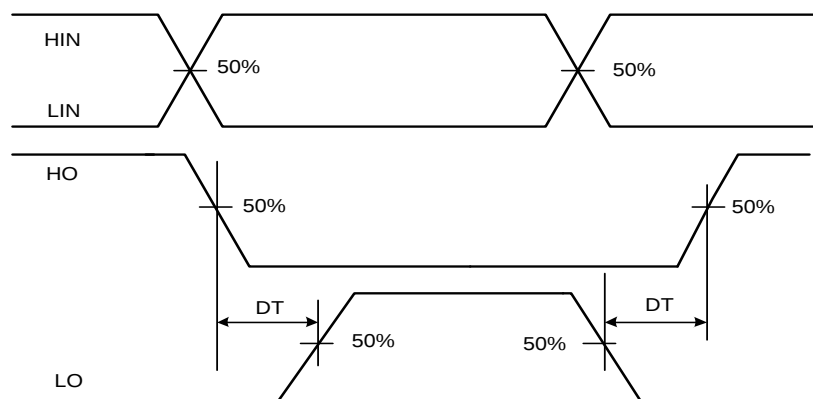
## 7 Cross-conduction Prevention

A protection circuit is specially designed inside the chip to enable cross-conduction prevention feature, which effectively prevents MOSFETs from damage when high-side and low-side input signals are interfered. The figure below shows how the protection circuit works.



## 8 Deadtime

The chip is designed with dedicated deadtime protection circuit. Both the high-side and low-side outputs are set to LOW during the deadtime. This feature prevents both MOSFETs of each half-bridge from switching on at the same time. The following figure shows the timing relation between deadtime, input signal and output signal.



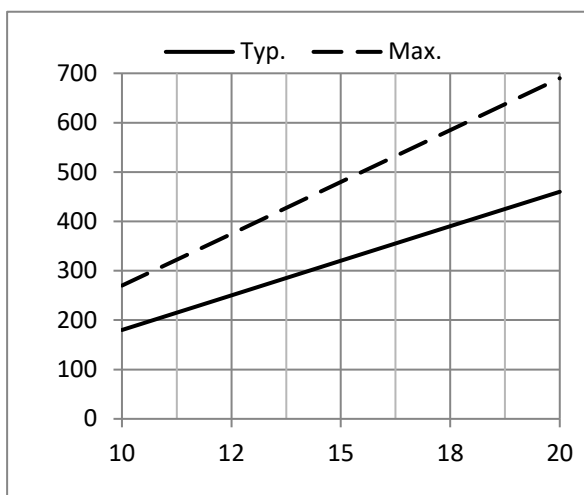


Figure 1A V<sub>CC</sub> Supply Current vs V<sub>CC</sub> Supply Voltage

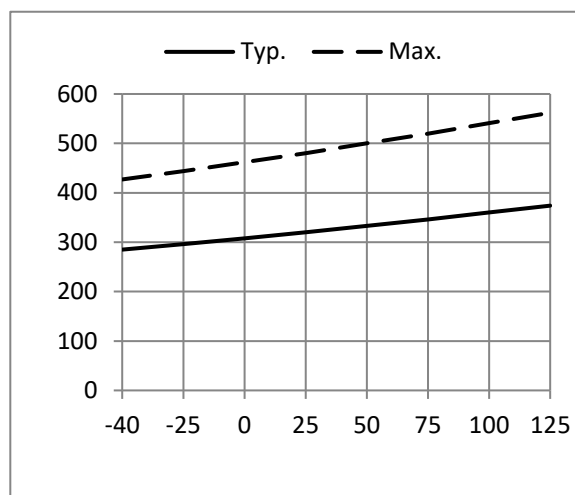


Figure 1B V<sub>CC</sub> Supply Current vs Temperature

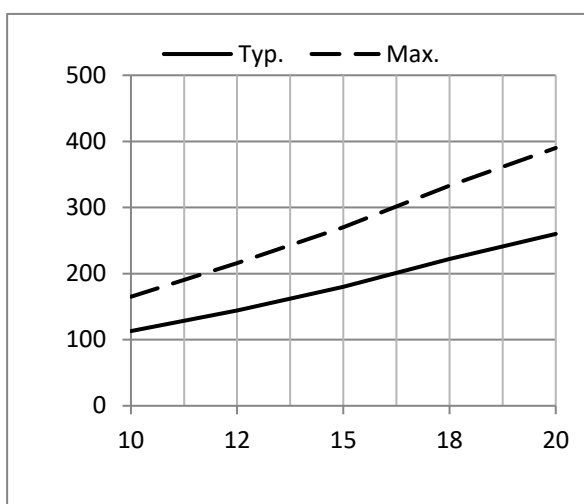


Figure 2A V<sub>BS</sub> Supply Current vs V<sub>BS</sub> Supply Voltage

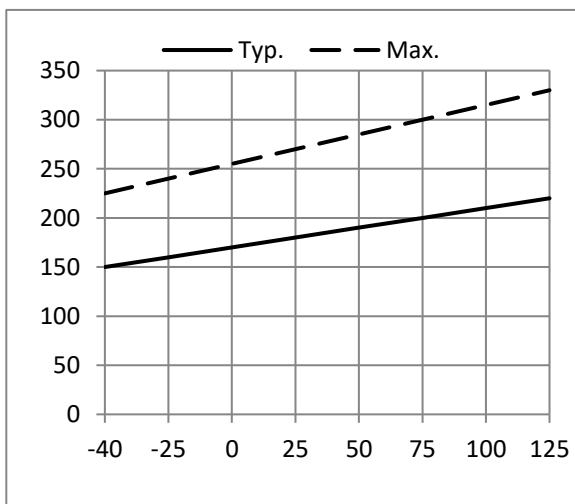


Figure 2B V<sub>BS</sub> Supply Current vs Temperature

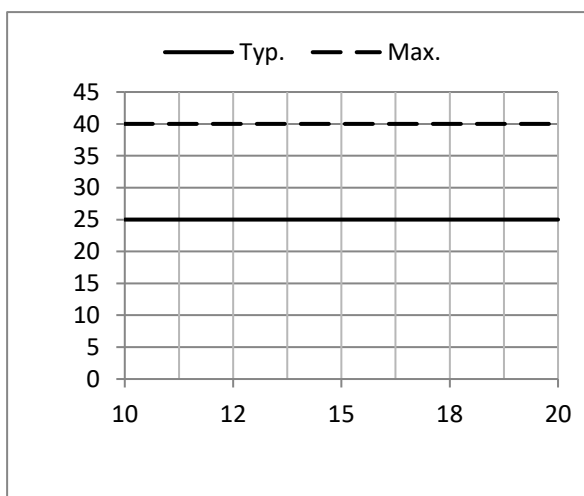


Figure 3A High-level Input Bias Current vs Supply Voltage

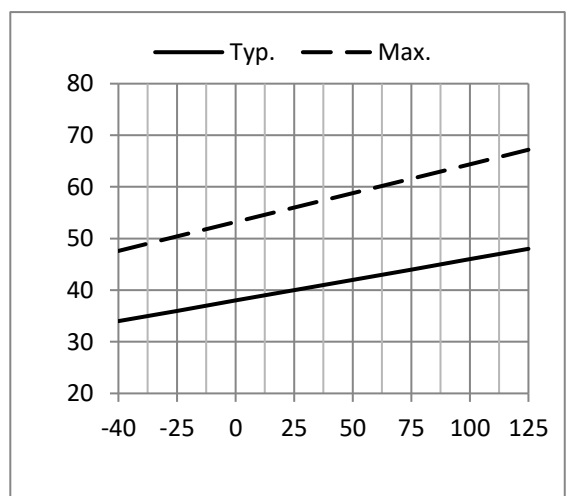


Figure 3B High-level Input Bias Current vs Temperature

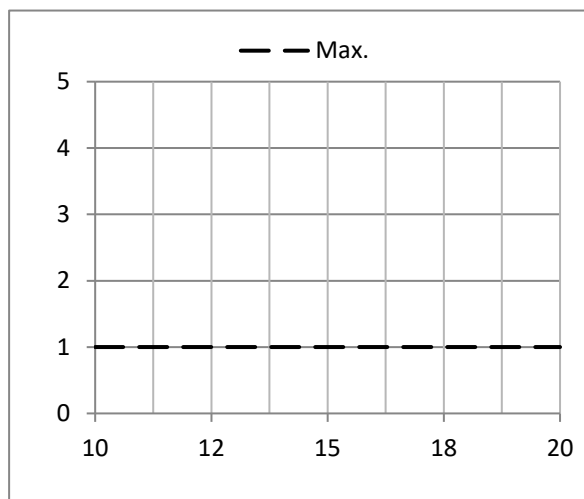


Figure 4A Low-level Input Bias Current vs Supply Voltage

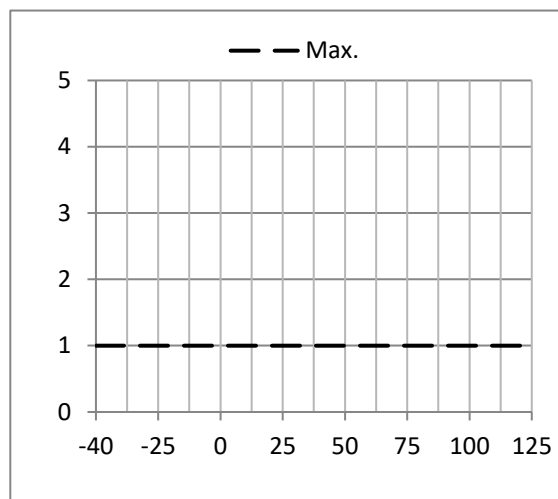


Figure 4B Low-level Input Bias Current vs Temperature

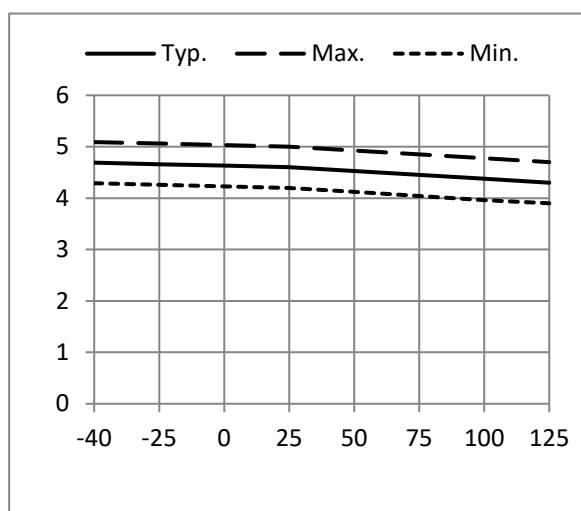


Figure 5A  $V_{CC}$  UVLO Threshold Voltage vs Temperature

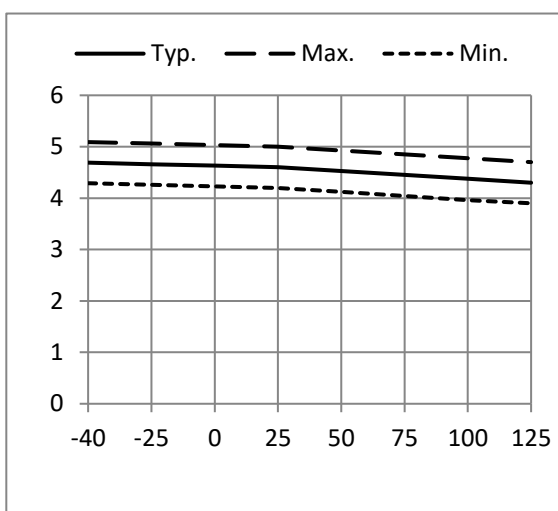


Figure 5B  $V_{CC}$  UVLO Reset Voltage vs Temperature

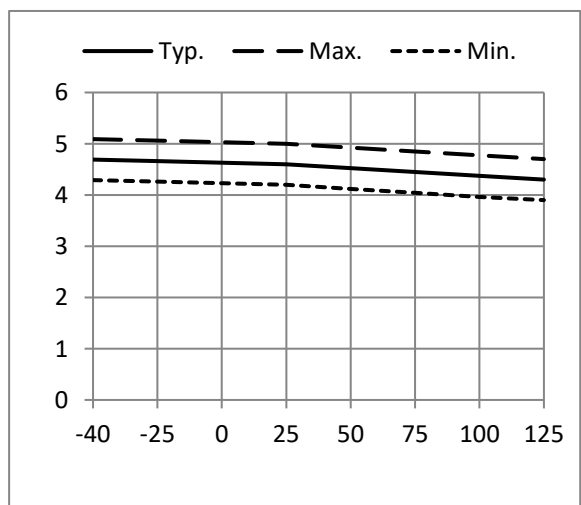


Figure 6A  $V_{BS}$  UVLO Threshold Voltage vs Temperature

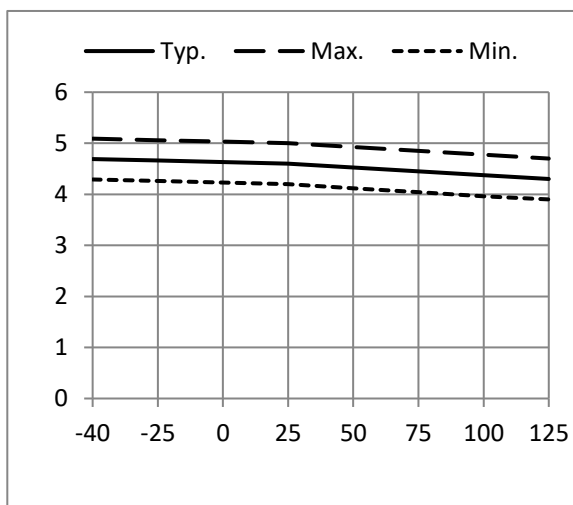


Figure 6B  $V_{BS}$  UVLO Reset Voltage vs Temperature

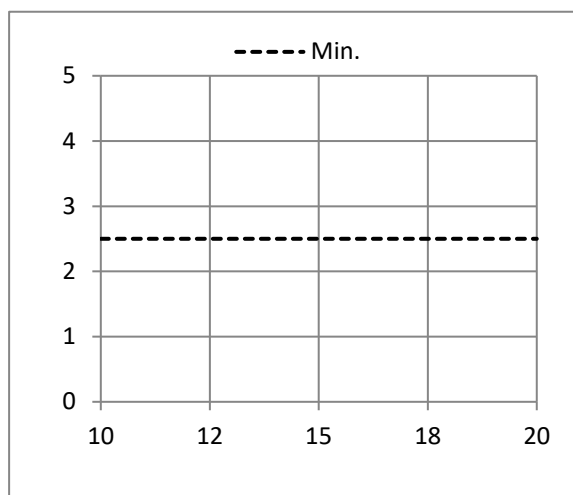


Figure 7A High-level Input Threshold Voltage vs Supply Voltage

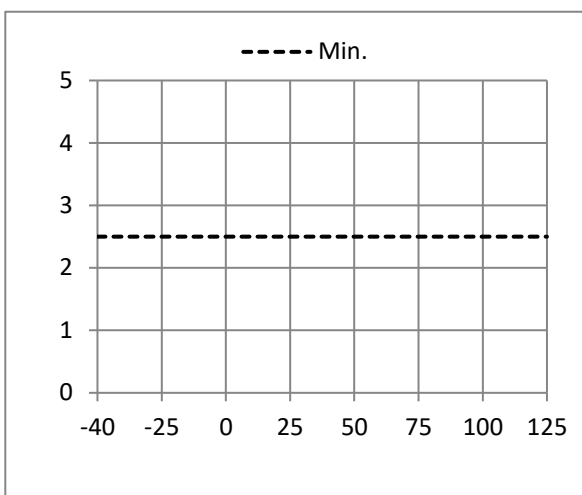


Figure 7B High-level Input Threshold Voltage vs Temperature

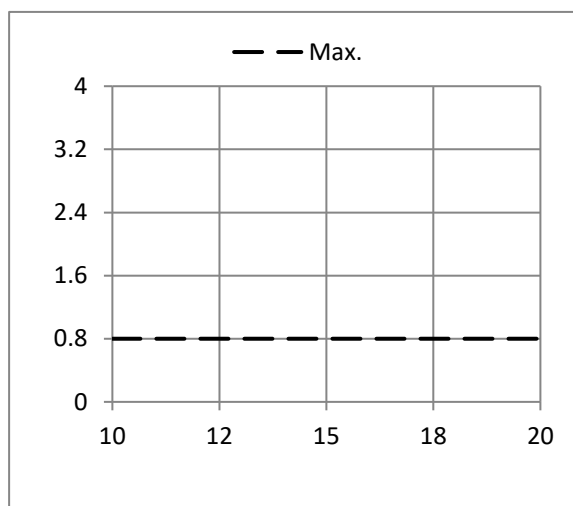


Figure 8A Low-level Input Threshold Voltage vs Supply Voltage

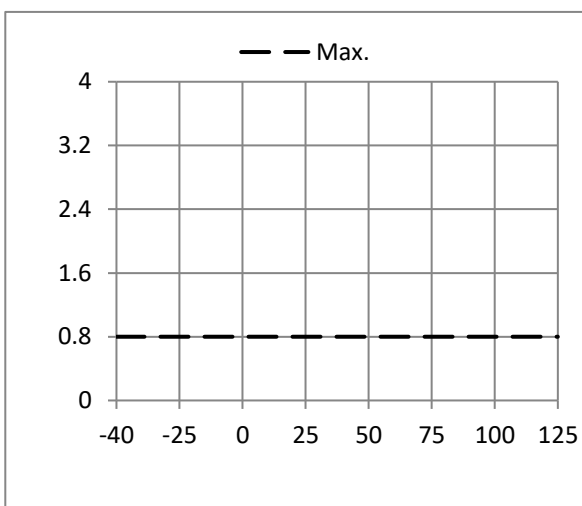


Figure 8B Low-level Input Threshold Voltage vs Temperature

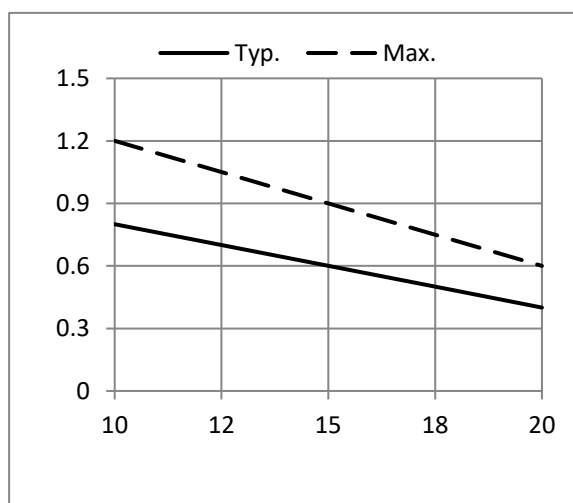


Figure 9A High-level Output Voltage vs Supply Voltage

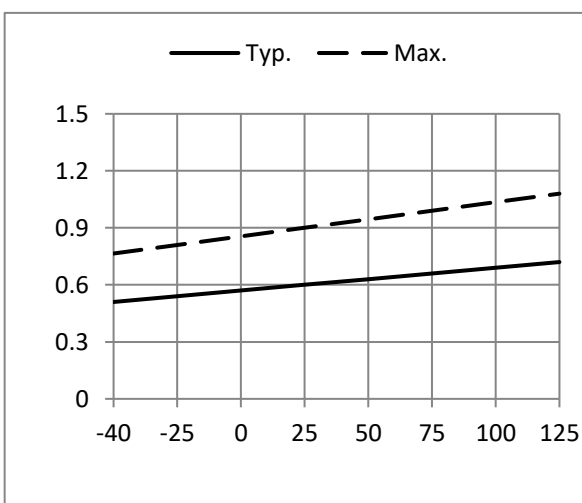


Figure 9B High-level Output Voltage vs Temperature

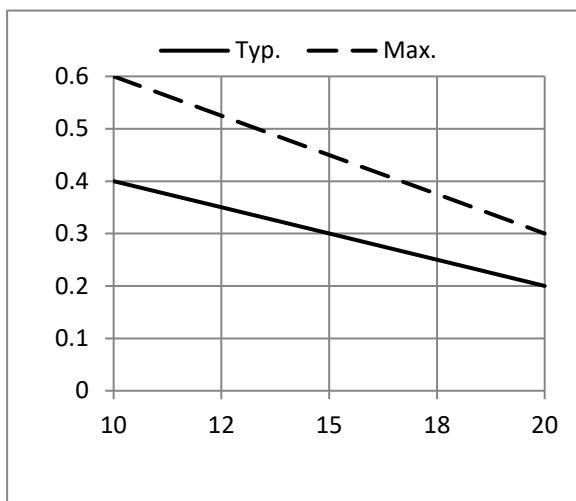


Figure 10A Low-level Output Voltage vs Supply Voltage

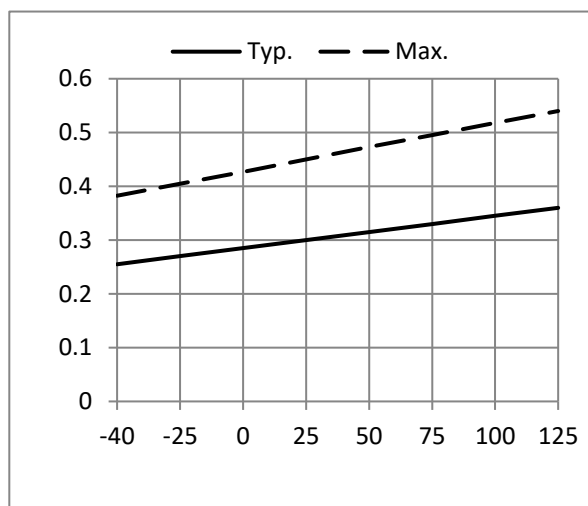


Figure 10B Low-level Output Voltage vs Temperature

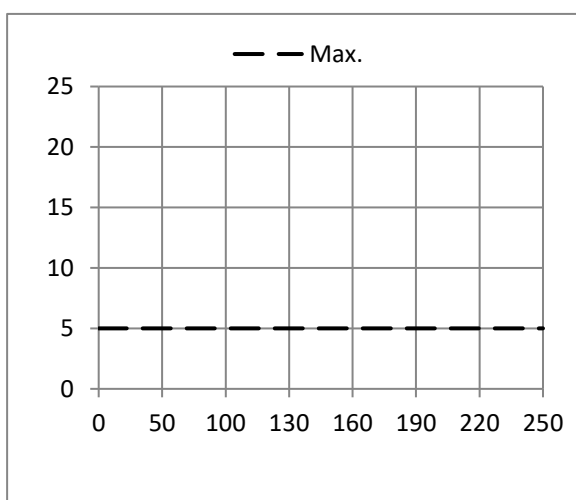


Figure 11A Leakage Current vs Supply Voltage

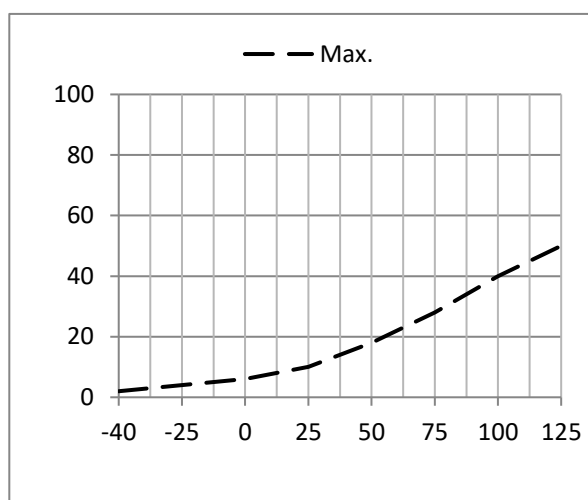


Figure 11B Leakage Current vs Temperature

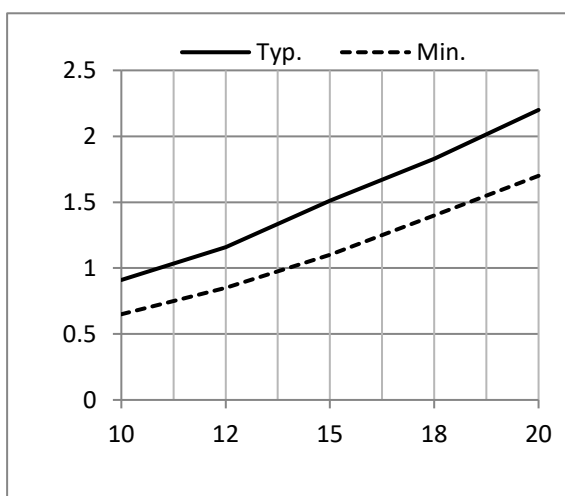


Figure 12A High-level Output Short-circuit

Pulse Current vs Supply Voltage

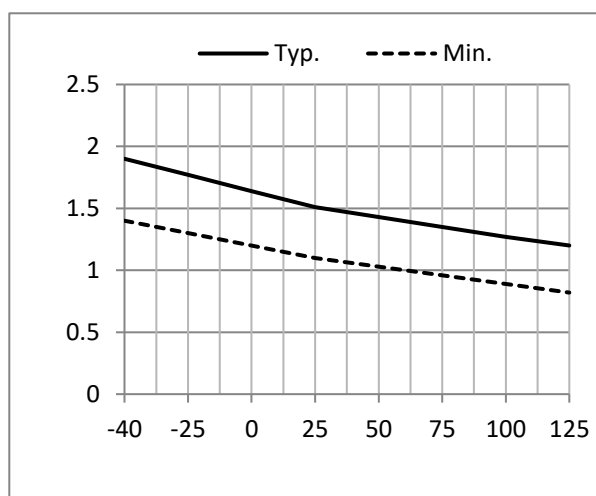


Figure 12B High-level Output Short-circuit

Pulse Current vs Temperature

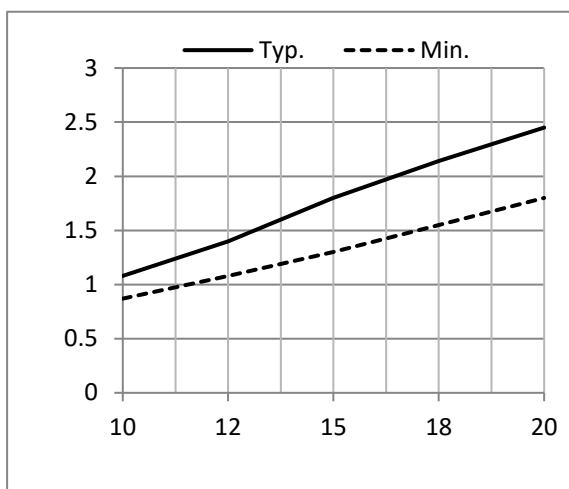


Figure 13A Low-level Output Short-circuit

Pulse Current vs Supply Voltage

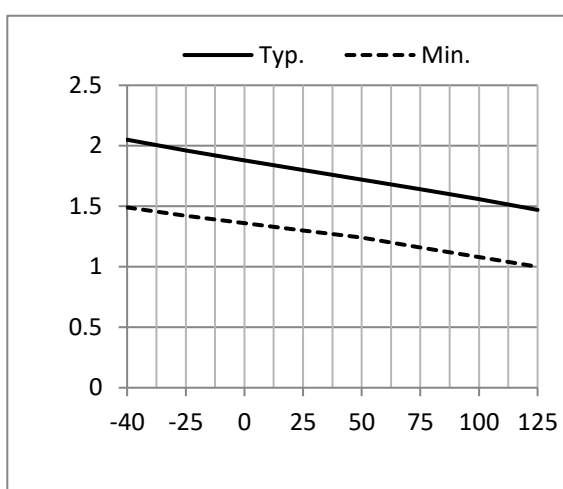


Figure 13B Low-level Output Short-circuit

Pulse Current vs Temperature

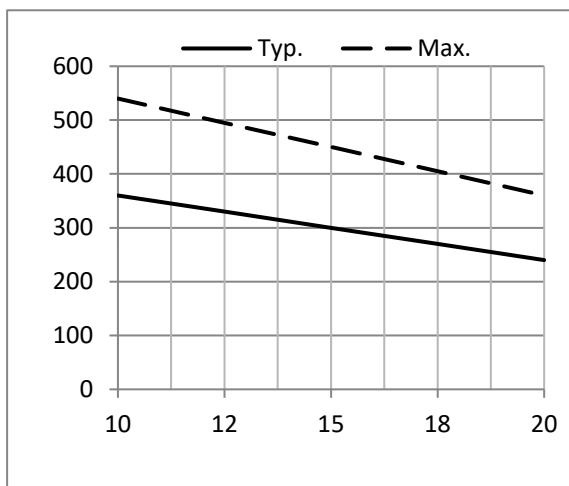


Figure 14A Turn-on Propagation Delay vs Supply Voltage

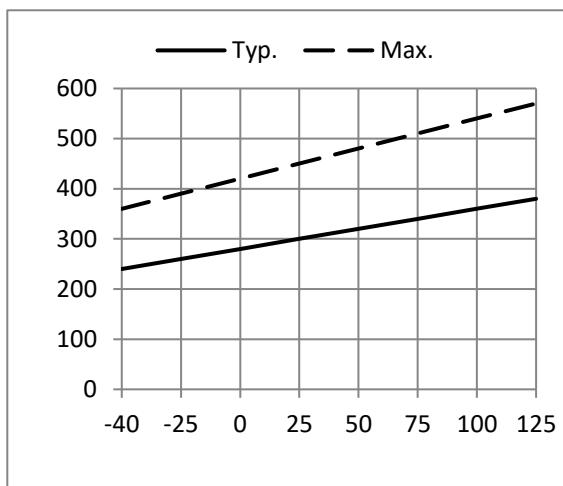


Figure 14B Turn-on Propagation Delay vs Temperature

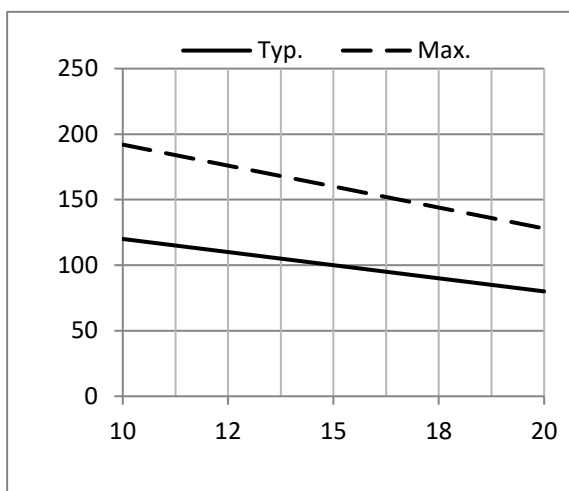


Figure 15A Turn-off Propagation Delay vs Supply Voltage

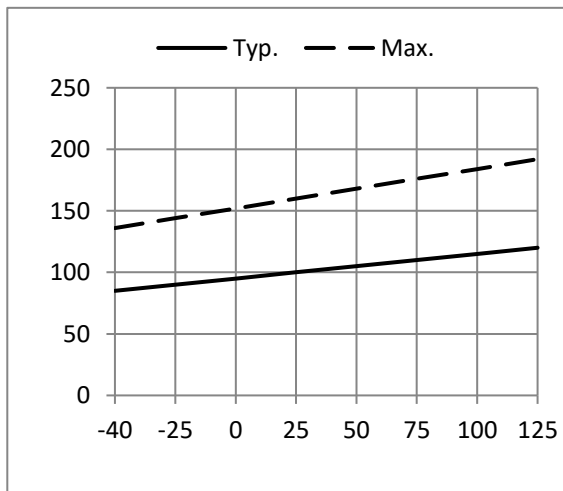


Figure 15B Turn-off Propagation Delay vs Temperature

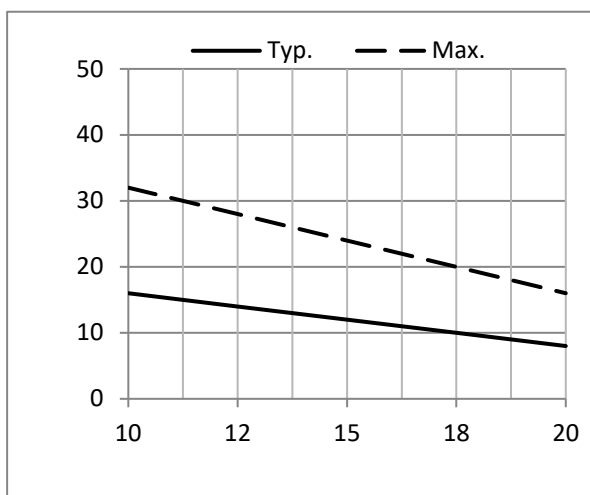


Figure 16A Turn-on Rise Time vs Supply Voltage

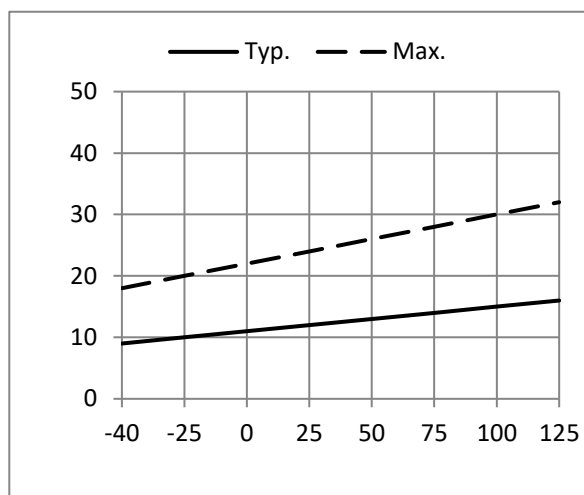


Figure 16B Turn-on Rise Time vs Temperature

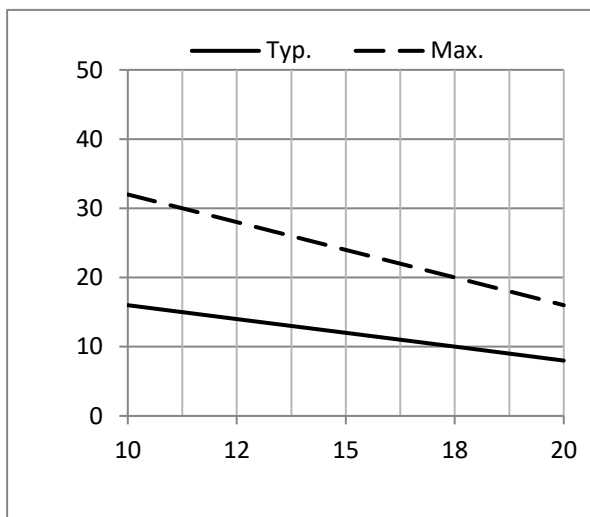


Figure 17A Turn-off Fall Time vs Supply Voltage

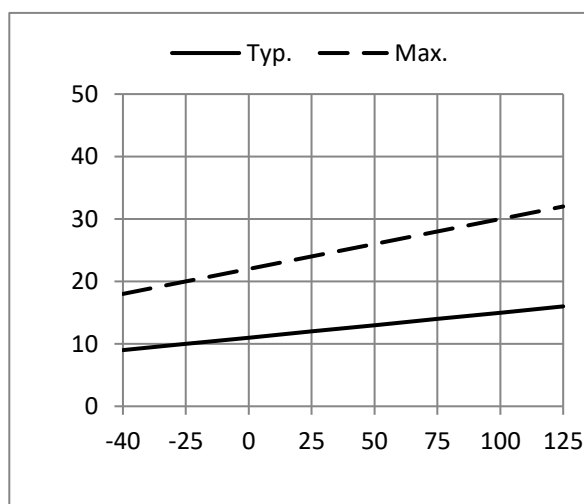


Figure 17B Turn-off Fall Time vs Temperature

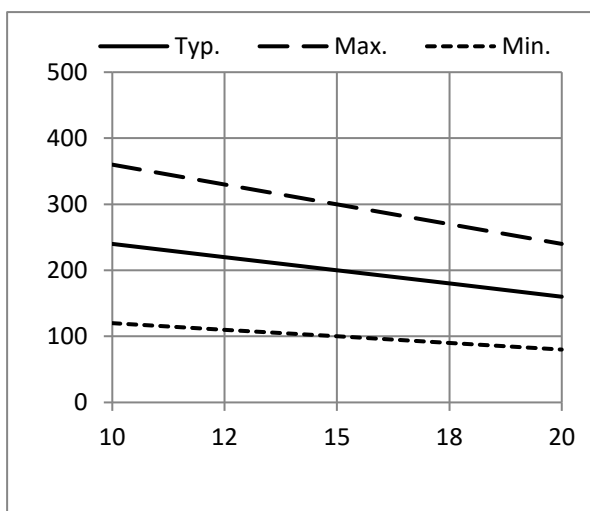


Figure 18A Deadtime vs Supply Voltage

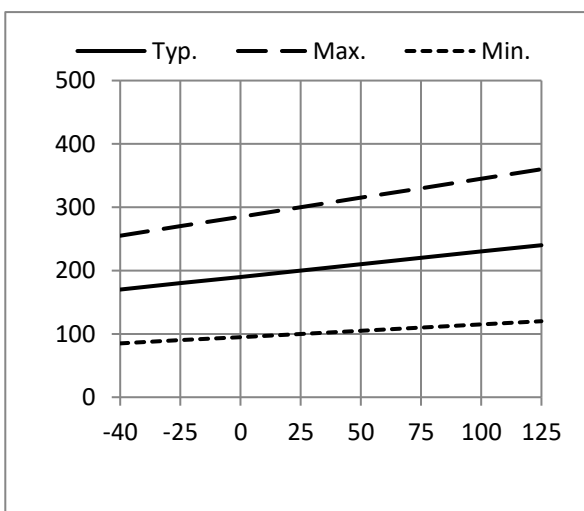


Figure 18B Deadtime vs Temperature

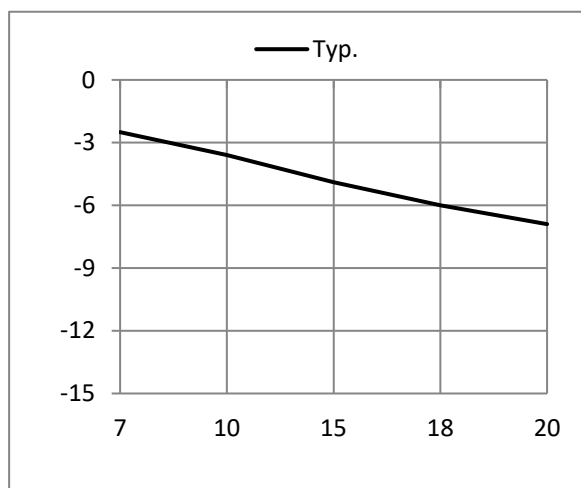


Figure 19A  $V_S$  Negative Offset vs Supply Voltage

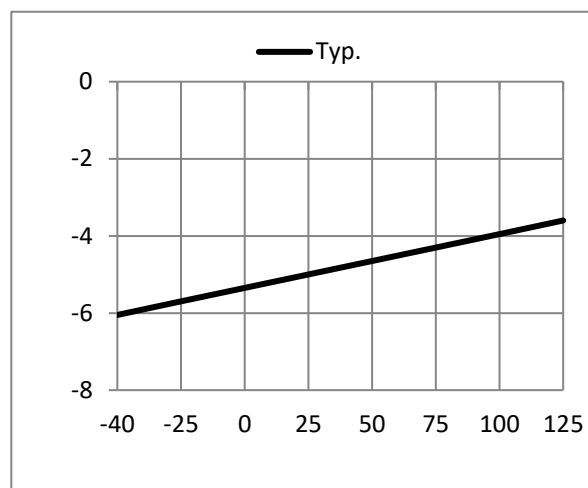


Figure 19B  $V_S$  Negative Offset vs Temperature

## 9 Revision History

| Rev. | Descriptions                                                                                                                                                                                                                                                                                                                                                                                         | Date       | Prepared By           |
|------|------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|------------|-----------------------|
| V1.0 | First release.                                                                                                                                                                                                                                                                                                                                                                                       | 2016/04/18 | Raymond Xie           |
| V1.1 | Added product model and changed FD6288 to FD6288T&Q.                                                                                                                                                                                                                                                                                                                                                 | 2016/12/18 | Raymond Xie           |
| V1.2 | Removed top-level silk prints and added packaging information.                                                                                                                                                                                                                                                                                                                                       | 2018/01/05 | Raymond Xie           |
| V1.3 | Proofread some descriptions.                                                                                                                                                                                                                                                                                                                                                                         | 2019/01/22 | Raymond Xie           |
| V1.4 | <ol style="list-style-type: none"> <li>Added R2 resistor and related descriptions in Typical Application Diagram;</li> <li>Corrected some descriptions and word spellings;</li> <li>Standardized document format.</li> </ol>                                                                                                                                                                         | 2023/04/24 | Lay Ye /<br>Eric Deng |
| V1.5 | <ol style="list-style-type: none"> <li>Proofread some descriptions in section 1 System Introduction;</li> <li>Separated section Pin Diagrams and section Pin Definitions by FD6288T and FD6288Q;</li> <li>Corrected some parameter names in section 3 Electrical Characteristics;</li> <li>Added Cross-conduction Prevention and Deadtime.</li> </ol>                                                | 2023/05/29 | Eric Deng             |
| V1.6 | <ol style="list-style-type: none"> <li>Updated section 1.6 Functional Block Diagram;</li> <li>Modified chapter 2 Package Information;</li> <li>Deleted “and it stays its logical state when <math>V_{S1,2,3}</math> ranges from (COM-4V) to (COM-<math>V_{BS}</math>)” in Note [3] of section 3.2 Recommended Operating Conditions;</li> <li>Modified chip model FD6288T&amp;Q as FD6288.</li> </ol> | 2023/09/01 | Eric Deng             |

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